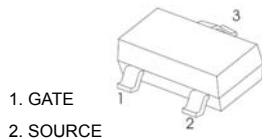
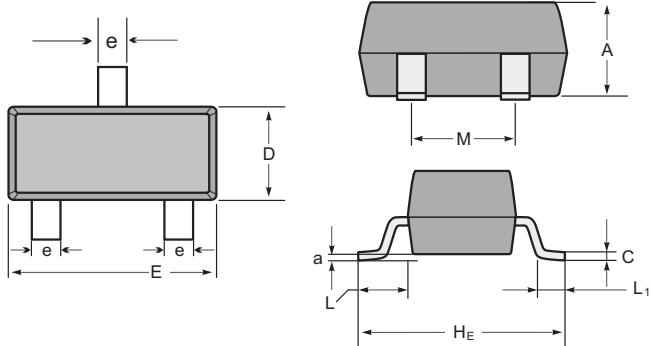
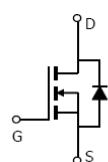


DESCRIPTION

The AO3404 uses advanced trench technology to provide excellent $R_{DS(ON)}$ and low gate charge. This device is suitable for use as a load switch or in PWM applications. The source leads are separated to allow a Kelvin connection to the source, which may be used to bypass the source inductance.

SOT-23

Marking

Product ID	Marking
AO3404	A49T

Equivalent Circuit

SOT-23 mechanical data

UNIT	A	C	D	E	H_E	e	M	L	L_1	a
mm	max	1.1	0.15	1.4	3.0	2.6	0.5	1.95	0.55 (ref)	0.36 (ref)
	min	0.9	0.08	1.2	2.8	2.2	0.3	1.7		
mil	max	43	6	55	118	102	20	77	22 (ref)	14 (ref)
	min	35	3	47	110	87	12	67		

Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	30	V
Gate-source voltage	V_{GS}	± 20	V
Continuous drain current ($t \leq 10\text{s}$)	I_D	5.8	A
Pulsed drain current *	I_{DM}	30	A
Thermal resistance from junction to ambient	$R_{\theta JA}$	357	°C/W
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55~150	°C

* Repetitive rating : Pulse width limited by maximum junction temperature.

AO3404

$T_a=25^\circ\text{C}$ unless otherwise specified

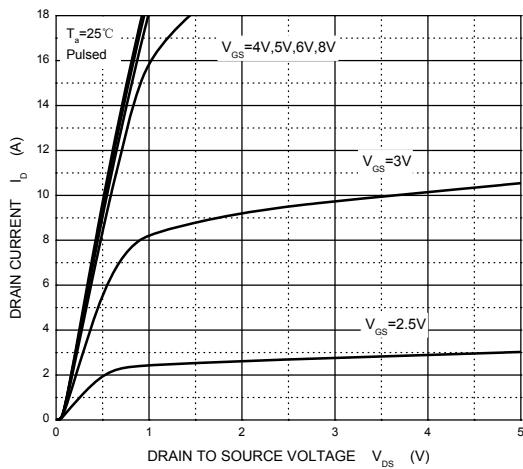
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 30V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1	1.4	3	V
Drain-source on-resistance (note 1)	$R_{DS(\text{on})}$	$V_{GS} = 10V, I_D = 5.8A$		19	30	$\text{m}\Omega$
		$V_{GS} = 4.5V, I_D = 4.8A$		31	42	$\text{m}\Omega$
Forward transconductance (note 1)	g_{FS}	$V_{DS} = 5V, I_D = 5.8A$	5			S
Diode forward voltage	V_{SD}	$I_S = 1A$			1	V
DYNAMIC PARAMETERS (note 2)						
Input capacitance	C_{iss}	$V_{DS} = 15V, V_{GS} = 0V, f = 1\text{MHz}$			820	pF
Output capacitance	C_{oss}			118		pF
Reverse transfer capacitance	C_{rss}			85		pF
Gate resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1\text{MHz}$			1.5	Ω
SWITCHING PARAMETERS (note 2)						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = 10V, V_{DS} = 15V, R_L = 2.6\Omega, R_{GEN} = 3\Omega$			6.5	ns
Turn-on rise time	t_r			3.1		ns
Turn-off delay time	$t_{d(off)}$			15.1		ns
Turn-off fall time	t_f			2.7		ns

Note :

1. Pulse Test : Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 0.5\%$.
2. These parameters have no way to verify.

RATING AND CHARACTERISTIC CURVES (AO3404)

Output Characteristics



Transfer Characteristics

